

**PRODUCT / PROCESS CHANGE NOTIFICATION**

**1. PCN basic data**

<b>1.1 Company</b>		STMicroelectronics International N.V
<b>1.2 PCN No.</b>	AMS/19/11724	
<b>1.3 Title of PCN</b>	Linear Voltage Regulators: New die Introduction for the L78xx series (5V, 12V and 15V Output Voltage versions) in HBIP40 Technology	
<b>1.4 Product Category</b>	See product list	
<b>1.5 Issue date</b>	2019-09-09	

**2. PCN Team**

<b>2.1 Contact supplier</b>	
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<b>2.1.3 Email</b>	kelly.murphy@st.com
<b>2.2 Change responsibility</b>	
<b>2.2.1 Product Manager</b>	Lorenzo NASO
<b>2.1.2 Marketing Manager</b>	Salvatore DI VINCENZO
<b>2.1.3 Quality Manager</b>	Sergio Tommaso SPAMPINATO

**3. Change**

<b>3.1 Category</b>	<b>3.2 Type of change</b>	<b>3.3 Manufacturing Location</b>
General Product & Design	Die redesign : Mask or mask set change with new die design like metallization (specifically chip frontside) or bug fix	ST Ang Mo Kio, Singapore

**4. Description of change**

	<b>Old</b>	<b>New</b>
<b>4.1 Description</b>	HBIP40 Technology	HBIP40 Technolgy : Layout Optimization, mainly consisting in EWS trimming structure removal (currently not used)
<b>4.2 Anticipated Impact on form,fit, function, quality, reliability or processability?</b>	No changes in term of Quality, Reliability and Electrical Characteristics	

**5. Reason / motivation for change**

<b>5.1 Motivation</b>	Following Divisional commitment towards a continuous improvement philosophy, an optimized layout has been implemented on some versions of L78xx product family housed in TO220 and D2PAK packages. Electrical characteristics remain unchanged. Quality and Reliability parameters are still guaranteed at the same level as in the past. The above changes will increase our flexibility and production capability on confirming orders that will be translated in a better service to our Customers.
<b>5.2 Customer Benefit</b>	SERVICE IMPROVEMENT

**6. Marking of parts / traceability of change**

<b>6.1 Description</b>	The traceability of the HBIP40 Technology parts will be ensured by different internal codification and QA number
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**7. Timing / schedule**

<b>7.1 Date of qualification results</b>	2019-08-12
<b>7.2 Intended start of delivery</b>	2019-12-06
<b>7.3 Qualification sample available?</b>	Upon Request

**8. Qualification / Validation**

<b>8.1 Description</b>	11724 W040-18-RAO_XA05-L78xx Layout Optimization_1.1.pdf
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8.2 Qualification report and qualification results	Available (see attachment)	Issue Date	2019-09-09
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**9. Attachments (additional documentations)**

11724 Public product.pdf 11724 W040-18-RAO_XA05-L78xx Layout Optimization_1.1.pdf	
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**10. Affected parts**

10.1 Current		10.2 New (if applicable)
10.1.1 Customer Part No	10.1.2 Supplier Part No	10.1.2 Supplier Part No
L7805ABD2T-TR	L7805ABD2T-TR	
L7805ABV	L7805ABV	
L7805ACV	L7805ACV	
L7805CD2T-TR	L7805CD2T-TR	
L7805CV	L7805CV	
L7812CV	L7812CV	
L7815CV	L7815CV	
L7812CD2T-TR	L7812CD2T-TR	

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## Public Products List

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**PCN Title** : Linear Voltage Regulators: New die Introduction for the L78xx series (5V, 12V and 15V Output Voltage versions) in HBIP40 Technology

**PCN Reference** : AMS/19/11724

**Subject** : Public Products List

Dear Customer,

Please find below the Standard Public Products List impacted by the change.

L7815CV	L7815ABD2T-TR	L7812ACD2T-TR
L7815CD2T-TR	L7805ABV	L7805ACV
L7815CV-DG	L7812CV	L7812ABV-DG
L7812ABV	L7812CV-DG	L7815ACV
L7812ABD2T-TR	L7815ACD2T-TR	L7815ABV-DG
L7805ABD2T-TR	L7812ACV	L7812CD2T-TR
L7805CV	L7805ABV-DG	L7805CV-DG
L7805ACV-DG	L7805CD2T-TR	L7815ABV
L7805ACD2T-TR	L7815ACV-DG	L7812ACV-DG



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**Qualification New Die / Layout  
 optimization on L78xx – HBIP40V  
 L7805ABV - XA05  
 TO220**

General Information	
<b>Product Line</b>	<i>XA0501</i>
<b>Product Description</b>	1.5 A positive voltage regulators
<b>P/N</b>	<i>L7805ABV</i>
<b>Product Group</b>	AMG
<b>Product division</b>	GENERAL PURPOSE ANALOG & RF
<b>Package</b>	TO220 - SINGLE GAUGE
<b>Silicon Process technology</b>	BiP HF
<b>Process Family</b>	<i>HBIP40V</i>
<b>Production mask set rev.</b>	LX00C REV A for DIE CODE: PXA
<b>Maturity level step</b>	30

Locations	
<b>Wafer fab</b>	SINGAPORE Ang Mo Kio
<b>Assembly plant</b>	SHENZHEN B/E
<b>Reliability Lab</b>	<i>Catania</i>
<b>Reliability assessment</b>	<i>Pass</i>

**DOCUMENT INFORMATION**

Version	Date	Pages	Prepared by	Approved by	Comment
1.0	January 2018	8	Alfio Rao	Giovanni Presti	Final Report
1.1	August 2019	8	Alfio Rao	Sergio Spampinato	Objective review

Note: This report is a summary of the reliability trials performed in good faith by STMicroelectronics in order to evaluate the potential reliability risks during the product life using a set of defined test methods.  
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## **1 APPLICABLE AND REFERENCE DOCUMENTS**

Document reference	Short description
JESD47	Stress-Test-Driven Qualification of Integrated Circuits

## **2 GLOSSARY**

DUT	Device Under Test
SS	Sample Size

## **3 RELIABILITY EVALUATION OVERVIEW**

### **3.1 Objectives**

Qualification of a new die layout optimization for L78xx series (5V, 12V and 15V Output Voltage versions) in HBIP40V Technology.

The change mainly consists in EWS trimming structure removal, resulting in a die size optimization.

In details, the Test Vehicle used for the qualification is L7805ABV - XA05 assembled in TO220 package.

### **3.2 Conclusion**

Qualification Plan requirements have been fulfilled without exception. It is stressed that reliability tests have shown that the devices behave correctly against environmental tests (no failure). Moreover, the stability of electrical parameters during the accelerated tests demonstrates the ruggedness of the products and safe operation, which is consequently expected during their lifetime.



## 4 DEVICE CHARACTERISTICS

### 4.1 Device description



The L78 series of three-terminal positive regulators is available in TO-220, TO-220FP, D<sup>2</sup>PAK and DPAK packages and several fixed output voltages, making it useful in a wide range of applications. These regulators can provide local on-card regulation, eliminating the distribution problems associated with single point regulation. Each type embeds internal current limiting, thermal shut-down and safe area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over

1 A output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltage and currents.

### 4.2 Construction note

P/N: L7805ABV	
<b>Wafer/Die fab. information</b>	
Wafer fab manufacturing location	SINGAPORE Ang Mo Kio
Technology	BiP HF
Process family	HBIP40V
Die finishing back side	CHROMIUM/NICKEL/SILVER
Die size	1,310, 1,470 micron
Passivation type	P-VAPOX/NITRIDE
<b>Wafer Testing (EWS) information</b>	
Electrical testing manufacturing location	Ang Mo Kio EWS
Tester	ETS300
Test program	XA051B601
<b>Assembly information</b>	
Assembly site	SHENZHEN B/E
Package description	TO220 - SINGLE GAUGE
Molding compound	Epoxy
Frame material	FRAME TO220 SG LCC Ve1 OpE/F3/G3 Bare Cu
Die attach material	Epoxy
Wires bonding materials/diameters	WIRE Cu D2 BL40-55g EL15-25% 500m
<b>Final testing information</b>	
Testing location	SHENZHEN B/E
Tester	QT200
Test program	XL05_01.cts #FA05

## 5 TESTS RESULTS SUMMARY

### 5.1 Test vehicle

Lot #	Diffusion Lot	Assy Lot	Technical Code	Package	Product Line	Part number
1	V6723T4T	GK7360VD	V3)K*XA051B6	TO220 - SINGLE GAUGE	XA05	L7805ABV

### 5.2 Test plan and results summary

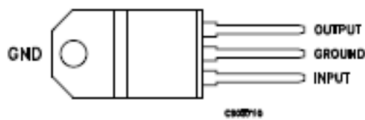
P/N: L7805ABV

Test	Std ref.	Conditions	SS	Steps	Failure/SS	Note
					Lot 1	
<b>Die Oriented Tests</b>						
HTOL	JESD22 A-108	T <sub>j</sub> = 125°C, BIAS 35 V	77	168 h	0/77	
				500 h	0/77	
				1000 h	0/77	
HTSL	JESD22 A-103	T <sub>a</sub> = 150°C	45	168 h	0/45	
				500 h	0/45	
				1000 h	0/45	
<b>Package Oriented Tests</b>						
AC	JESD22 A-102	P <sub>a</sub> =2Atm / T <sub>a</sub> =121°C	77	168 h	0/77	
TC	JESD22 A-104	T <sub>a</sub> = -65°C to 150°C	77	100 cy	0/77	
				200 cy	0/77	
				500 cy	0/77	
THB	JESD22 A-101	T <sub>a</sub> = 85°C, RH = 85%, BIAS 24 V	77	168 h	0/77	
				500 h	0/77	
				1000 h	0/77	
<b>Other Tests</b>						
ESD	JESD22-A114	HBM	3	+/-2000V	Pass	
	JESD22-C101	CDM	3	+/-500V	Pass	

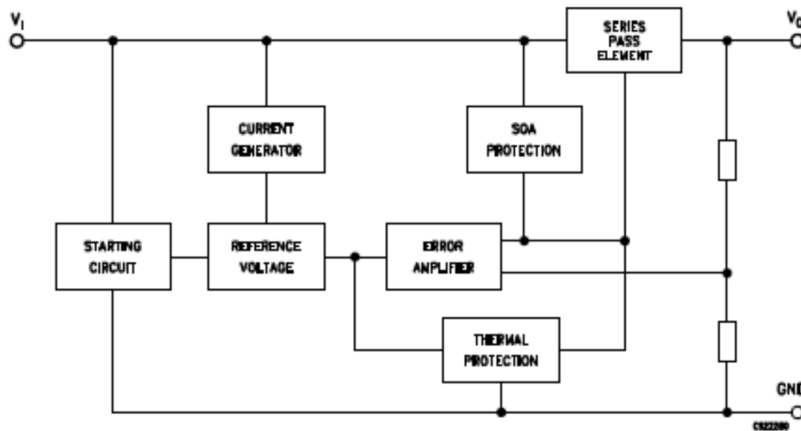
## 6 ANNEXES

### 6.1 Device details

#### 6.1.1 Pin connection



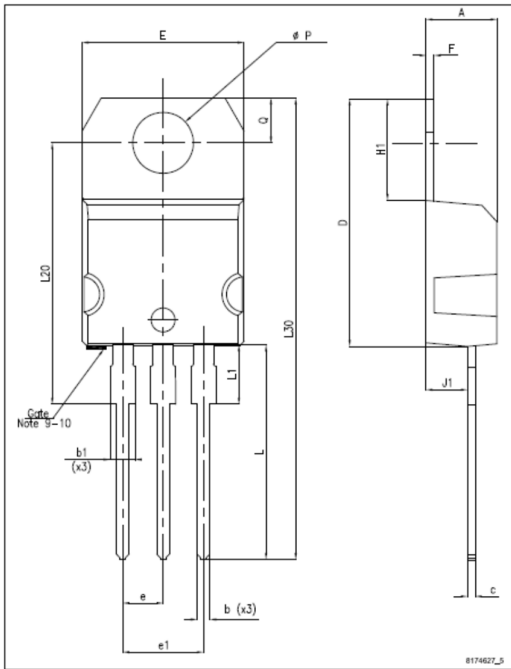
#### 6.1.2 Block diagram



### 6.1.3 Package outline/Mechanical data

## TO-220 (single gauge) package information

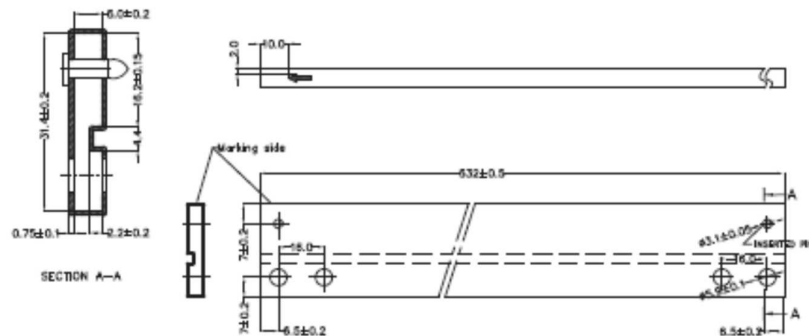
TO-220 (single gauge) package outline



TO-220 (single gauge) mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.80
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
E	10.00		10.40
e	2.40		2.70
e1	4.95		5.15
F	0.51		0.80
H1	6.20		6.60
J1	2.40		2.72
L	13.00		14.00
L1	3.50		3.93
L20		16.40	
L30		28.90	
øP	3.75		3.85
Q	2.65		2.95

Tube for TO-220 (single gauge) (mm.)



## 6.2 Tests Description

Test name	Description	Purpose
<b>Die Oriented</b>		
<b>HTOL</b> High Temperature Operating Life	The device is stressed in static or dynamic configuration, approaching the operative max. absolute ratings in terms of junction temperature and bias condition.	To determine the effects of bias conditions and temperature on solid state devices over time. It simulates the devices' operating condition in an accelerated way. The typical failure modes are related to, silicon degradation, wire-bonds degradation, oxide faults.
<b>HTSL</b> High Temperature Storage Life	The device is stored in unbiased condition at the max. temperature allowed by the package materials, sometimes higher than the max. operative temperature.	To investigate the failure mechanisms activated by high temperature, typically wire-bonds solder joint ageing, data retention faults, metal stress-voiding.
<b>Package Oriented</b>		
<b>AC</b> Auto Clave (Pressure Pot)	The device is stored in saturated steam, at fixed and controlled conditions of pressure and temperature.	To investigate corrosion phenomena affecting die or package materials, related to chemical contamination and package hermeticity.
<b>TC</b> Temperature Cycling	The device is submitted to cycled temperature excursions, between a hot and a cold chamber in air atmosphere.	To investigate failure modes related to the thermo-mechanical stress induced by the different thermal expansion of the materials interacting in the die-package system. Typical failure modes are linked to metal displacement, dielectric cracking, molding compound delamination, wire-bonds failure, die-attach layer degradation.
<b>THB</b> Temperature Humidity Bias	The device is biased in static configuration minimizing its internal power dissipation, and stored at controlled conditions of ambient temperature and relative humidity.	To evaluate the package moisture resistance with electrical field applied, both electrolytic and galvanic corrosion are put in evidence.
<b>Other</b>		
<b>ESD</b> Electro Static Discharge	The device is submitted to a high voltage peak on all his pins simulating ESD stress according to different simulation models. <b>CDM:</b> Charged Device Model	To classify the device according to his susceptibility to damage or degradation by exposure to electrostatic discharge.